Complementary ThermalTrak[™] Transistors

The ThermalTrak family of devices has been designed to eliminate thermal equilibrium lag time and bias trimming in audio amplifier applications. They can also be used in other applications as transistor die protection devices.

Features

- Thermally Matched Bias Diode
- Instant Thermal Bias Tracking
- Absolute Thermal Integrity
- High Safe Operating Area
- Pb–Free Packages are Available*

Benefits

- Eliminates Thermal Equilibrium Lag Time and Bias Trimming
- Superior Sound Quality Through Improved Dynamic Temperature Response
- Significantly Improved Bias Stability
- Simplified Assembly
 - Reduced Labor Costs
 - Reduced Component Count
- High Reliability

Applications

- High-End Consumer Audio Products
 - Home Amplifiers
 - Home Receivers
- Professional Audio Amplifiers
 - Theater and Stadium Sound Systems
 - Public Address Systems (PAs)



ON Semiconductor®

http://onsemi.com

BIPOLAR POWER TRANSISTORS 15 AMP, 260 VOLT, 180 WATT



TO-264, 5 LEAD CASE 340AA STYLE 1

MARKING DIAGRAM

SCHEMATIC



NJL0xxxD = Device Code

	xxx = 281 or 302
G	= Pb–Free Package
A	= Assembly Location
YY	= Year
WW	=Work Week

ORDERING INFORMATION

Device	Package	Shipping
NJL0281D	TO-264	25 Units / Rail
NJL0281DG	TO–264 (Pb–Free)	25 Units / Rail
NJL0302D	TO-264	25 Units / Rail
NJL0302DG	TO–264 (Pb–Free)	25 Units / Rail

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS (T_J = $25^{\circ}C$ unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	260	Vdc
Collector-Base Voltage	V _{CBO}	260	Vdc
Emitter-Base Voltage	V _{EBO}	5	Vdc
Collector-Emitter Voltage - 1.5 V	V _{CEX}	260	Vdc
Collector Current – Continuous – Peak (Note 1)	I _C	15 25	Adc
Base Current – Continuous	I _B	1.5	Adc
Total Power Dissipation @ $T_C = 25^{\circ}C$ Derate Above 25°C	PD	180 1.43	W ₩/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	– 65 to +150	°C
DC Blocking Voltage	V _R	200	V
Average Rectified Forward Current	I _{F(AV)}	1.0	А

THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit
Thermal Resistance, Junction-to-Case	$R_{ extsf{ heta}JC}$	0.694	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability. 1. Pulse Test: Pulse Width = 5 ms, Duty Cycle < 10%.

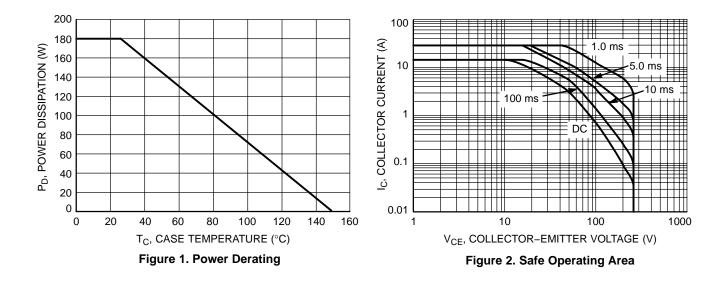
ATTRIBUTES

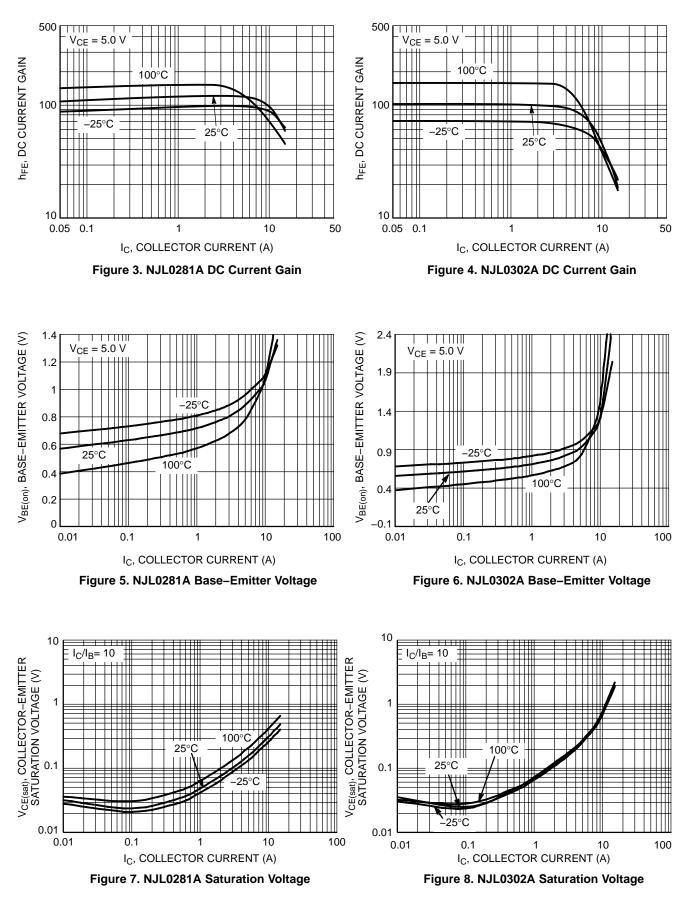
	Characteristic	Value
ESD Protection	Human Body Model Machine Model	
Flammability Rating		UL 94 V–0 @ 0.125 in

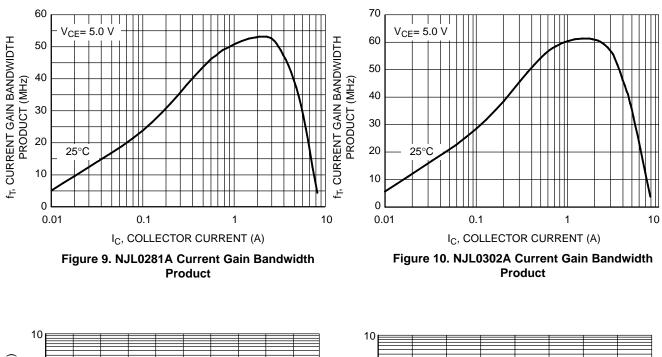
ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Sustaining Voltage $(I_C = 100 \text{ mAdc}, I_B = 0)$	V _{CEO(sus)}	260	_	Vdc
Collector Cutoff Current ($V_{CB} = 260 \text{ Vdc}, I_E = 0$)	I _{CBO}	_	10	μAdc
Emitter Cutoff Current ($V_{EB} = 5 \text{ Vdc}, I_C = 0$)	I _{EBO}	_	5	μAdc
ON CHARACTERISTICS				
DC Current Gain ($I_C = 500 \text{ mAdc}, V_{CE} = 5 \text{ Vdc}$) ($I_C = 1 \text{ Adc}, V_{CE} = 5 \text{ Vdc}$) ($I_C = 3 \text{ Adc}, V_{CE} = 5 \text{ Vdc}$)	h _{FE}	75 75 75	150 150 150	
Collector–Emitter Saturation Voltage $(I_C = 5 \text{ Adc}, I_B = 0.5 \text{ Adc})$	V _{CE(sat)}	_	1.0	Vdc
Base–Emitter On Voltage ($I_C = 5 \text{ Adc}, V_{CE} = 5 \text{ Vdc}$)	V _{CE(on)}	_	1.2	Vdc
DYNAMIC CHARACTERISTICS				
Current–Gain – Bandwidth Product ($I_C = 1 \text{ Adc}, V_{CE} = 5 \text{ Vdc}, f_{test} = 1 \text{ MHz}$)	f _T	30	_	MHz
Output Capacitance (V_{CB} = 10 Vdc, I _E = 0, f _{test} = 1 MHz)	C _{ob}	_	400	pF
Maximum Instantaneous Forward Voltage (Note 2) ($i_F = 1.0 \text{ A}, T_J = 25^{\circ}\text{C}$) ($i_F = 1.0 \text{ A}, T_J = 150^{\circ}\text{C}$)	VF		.1 93	V
Maximum Instantaneous Reverse Current (Note 2) (Rated dc Voltage, $T_J = 25^{\circ}C$) (Rated dc Voltage, $T_J = 150^{\circ}C$)	i _R		10 00	μΑ
Maximum Reverse Recovery Time (i _F = 1.0 A, di/dt = 50 A/μs)	t _{rr}	1	00	ns

2. Diode Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.







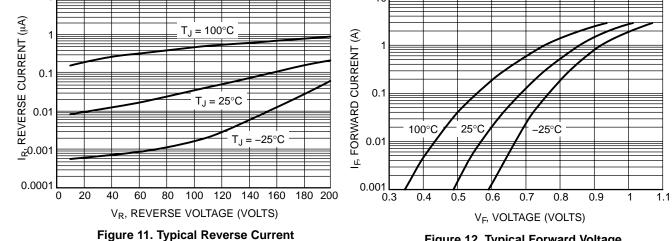
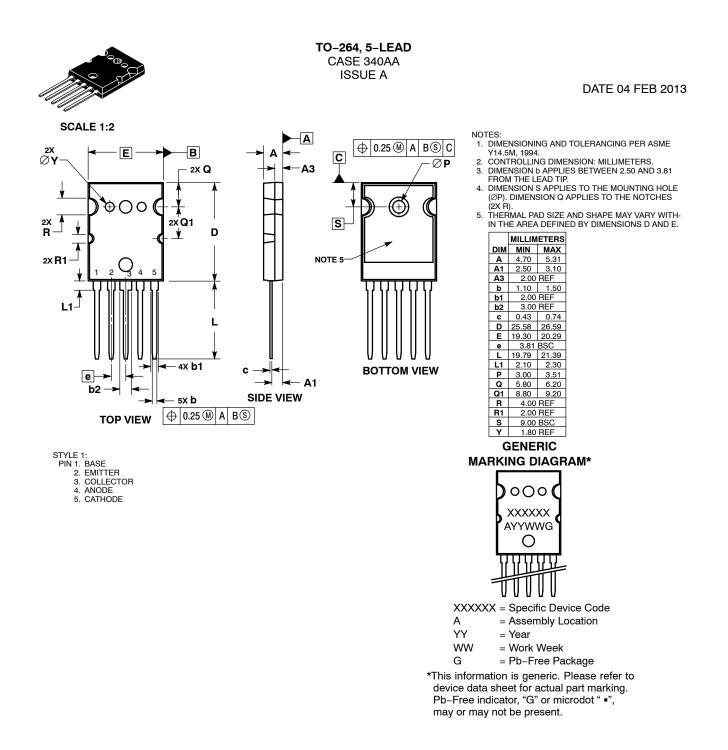


Figure 12. Typical Forward Voltage

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DESCRIPTION:	TO-264, 5-LEAD		PAGE 1 OF 1

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